

# DTA143ZK

## PNP Digital Transistor

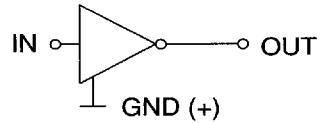
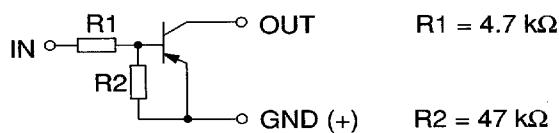
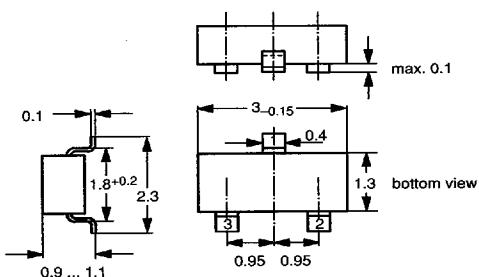
with built-in bias resistor. This allows inverter circuit configuration without external resistors for input.

The pin configuration is the following:

1 = Collector/OUT

2 = Base/IN

3 = Emitter/GND



Equivalent circuit

Plastic Package JEDEC TO-236  
23 A 3 according to DIN 41869  
The case is impervious to light.

Weight approximately 0.008 g  
Dimensions in mm

## Absolute Maximum Ratings

	Symbol	Value	Unit
Supply Voltage	$-V_{SUP}$	50	V
Input Voltage	$-V_I$	30	V
	$V_I$	5	V
Collector Current	$-I_C$	100	mA
Peak Collector Current	$-I_{CM}$	100	mA
Power Dissipation	$P_{tot}$	200 <sup>1)</sup>	mW
Junction Temperature	$T_j$	125	°C
Storage Temperature Range	$T_s$	-55 to +125	°C

1) Device on fiberglass substrate 30 mm x 10 mm, pad size 2 mm x 2 mm

**Characteristics at  $T_{amb} = 25^{\circ}\text{C}$** 

	Symbol	Min.	Typ.	Max.	Unit
Input OFF Voltage at $-V_{SUP} = 5 \text{ V}$ , $-I_O = 100 \mu\text{A}$	$-V_{I(OFF)}$	0.5	—	—	V
Input ON Voltage at $-V_O = 0.3 \text{ V}$ , $-I_O = 5 \text{ mA}$	$-V_{I(ON)}$	—	—	1.3	V
Output ON Voltage at $-I_O = 5 \text{ mA}$ , $-I_I = 0.25 \text{ mA}$	$-V_{O(ON)}$	—	0.1	0.3	V
Input Current at $-V_I = 5 \text{ V}$ ,	$-I_I$	—	—	1.8	mA
Output OFF Current at $-V_{SUP} = 30 \text{ V}$ , $V_I = 0 \text{ V}$	$-I_{O(OFF)}$	—	—	10	$\mu\text{A}$
DC Current Gain at $-I_O = 10 \text{ mA}$ , $-V_O = 5 \text{ V}$	$G_I$	80	—	—	—
Input Resistance	$R_I$	—	4.7	—	k $\Omega$
Resistance Ratio	$R_2/R_1$	8	10	12	—
Transition Frequency at $-V_{CE} = 10 \text{ V}$ , $I_E = 5 \text{ mA}$	$f_T$	—	250	—	MHz